

SavantIC Semiconductor

Product Specification

Silicon PNP Power Transistors

2SA1667 2SA1668

DESCRIPTION

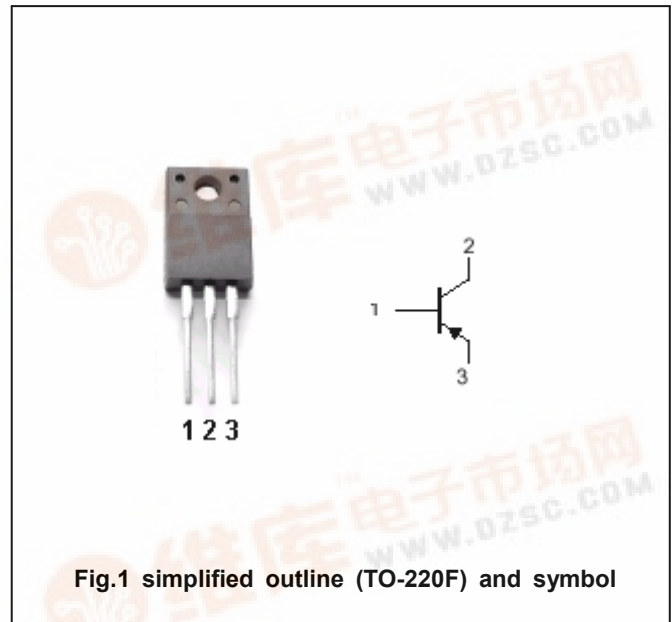
- With TO-220F package
- Complement to type 2SC4381/4382

APPLICATIONS

- For TV vertical output ,audio output driver and general purpose applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter



Absolute maximum ratings ($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	Open emitter	-150	V
			-200	
V_{CEO}	Collector-emitter voltage	Open base	-150	V
			-200	
V_{EBO}	Emitter-base voltage	Open collector	-6	V
I_C	Collector current		-2	A
I_B	Base current		-1	A
P_C	Collector dissipation	$T_C=25^\circ\text{C}$	25	W
T_j	Junction temperature		150	$^\circ\text{C}$
T_{stg}	Storage temperature		-55~150	$^\circ\text{C}$

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CHARACTERISTICS

T_j=25℃ unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	2SA1667	I _C =-25mA ; I _B =0	-150			V
		2SA1668		-200			
V _{CEsat}	Collector-emitter saturation voltage		I _C =-0.7A; I _B =-70mA			-1.0	V
I _{CBO}	Collector cut-off current	2SA1667	V _{CB} =-150V; I _E =0			-10	μA
		2SA1668	V _{CB} =-200V; I _E =0			-10	μA
I _{EBO}	Emitter cut-off current		V _{EB} =-6V; I _C =0			-10	μA
h _{FE}	DC current gain		I _C =-0.7A ; V _{CE} =-10V	60			
f _T	Transition frequency		I _C =-0.2A ; V _{CE} =-12V		20		MHz
C _{OB}	Output capacitance		I _E =0 ; V _{CB} =10V; f=1MHz		60		pF

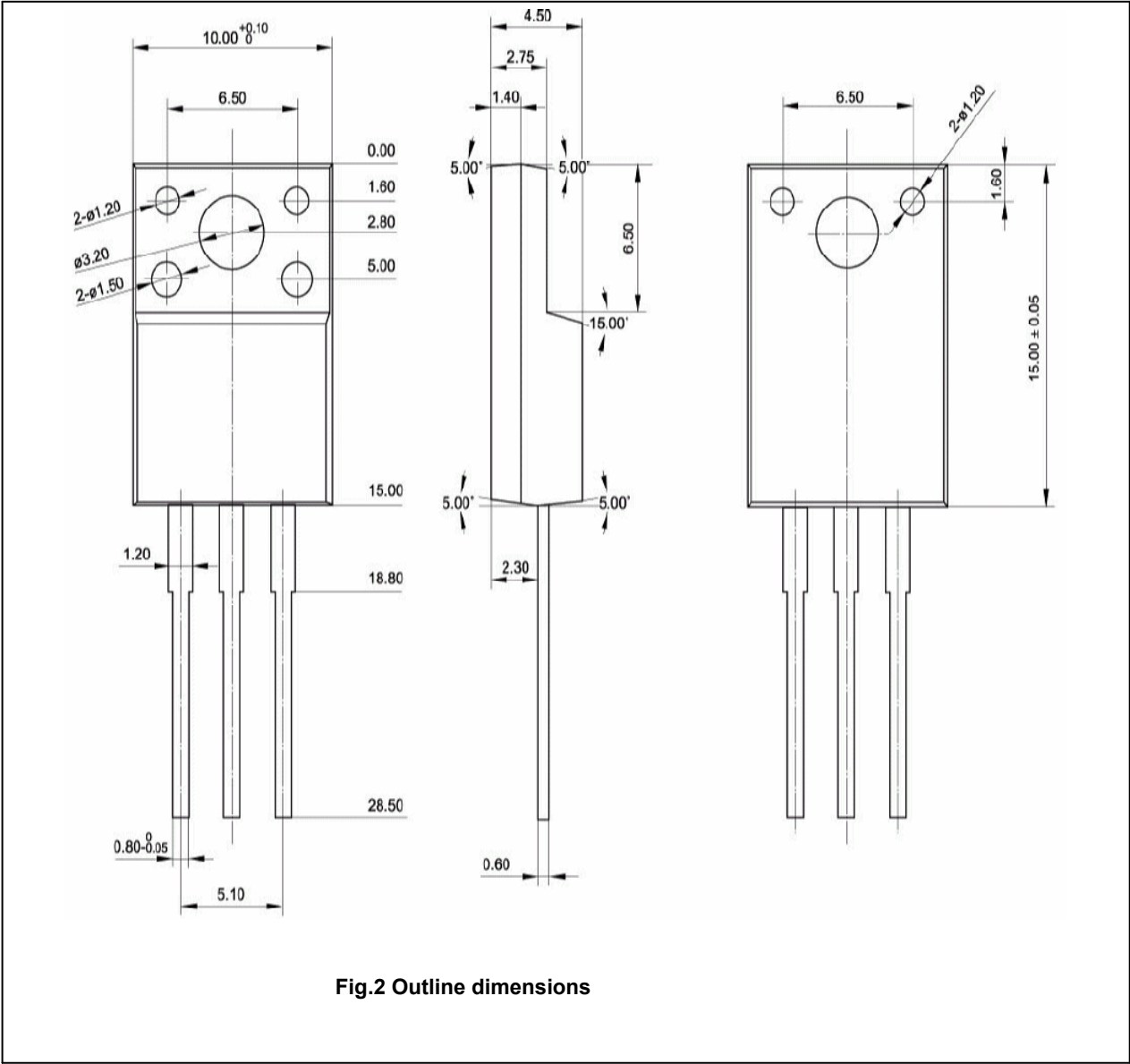
Switching time

t _{on}	Turn-on time	I _C =-1A ; I _{B1} =-I _{B2} =-0.1A V _{CC} =-20V , R _L =20Ω		0.40		μs
t _s	Storage time			1.50		μs
t _f	Fall time			0.50		μs

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PACKAGE OUTLINE



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